

# HD29468

# Triple Line Drivers/Receivers

REJ03D0307-0200Z (Previous ADE-205-583 (Z)) Rev.2.00 Jul.16.2004

## **Description**

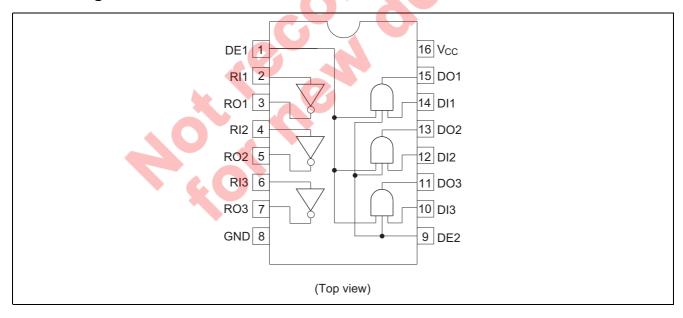
The HD29468 features line drivers and receivers for unbalanced transmissions, which meet the specs of IBM 360 and 370. This device has three drivers and receivers in one package. Input of driver and output of receiver are compatible with low power schottky TTL circuit and operates from a single 5 V power supply. The driver has two types of enable inputs. Sprius noise can be prevented by grounding either input when power supply is throw or cut off. The outputs are protected from short circuit and the wired logic is available due to emitter follower from for party line data bus applications. The device operates at high speed. Low to high level and high to low level propagation delay times defference are 10 ns max.

#### **Features**

• Ordering Information

Part Name	Package Type	Package Code	Package	Taping Abbreviation
			Abbreviation	(Quantity)
HD29468P	DILP-16 pin	DP-16E, -16FV	P	_

## **Pin Arrangement**



## **Function Table**

Driver				Receiver	
IInput			Output	Input	Output
DI	DE1	DE2	DO	RI	RO
L	Х	Х	L	L	Н
X	L	Х	L	Н	L
X	Х	L	L		
Н	Н	Н	Н		

H: High levelL: Low levelX: Immaterial

## **Absolute Maximum Ratings**

Item	Symbol	Ratings	Unit
Supply Voltage	V <sub>cc</sub>	+7	V
Driver Input Voltage	$V_{ID}$	-0.5 to +7	V
Driver Output Voltage	V <sub>OD</sub>	-0.5 to +7	V
Receiver Input Voltage	$V_{IR}$	-0.5 to +7	V
Power Dissipation (Ta = 25°C)*1	DP	1000	mW
	FP	785	•
Operating Temperature	Та	0 to +75	°C
Storage Temperature	Tstg	-65 to +150	°C

Notes: 1. The above data were taken by the  $\Delta V_{BE}$  method, mounting on a glass epoxy board (40 × 40 × 1.6 mm) of 10% wiring density.

2. The absolute maximum ratings are values which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

## **Recommended Operating Conditions**

Item	Symbol	Min	Тур	Max	Unit
Supply Voltage	$V_{CC}$	4.75	5.00	5.25	V
Operating Temperature	Та	0	_	75	°C

## **Electrical Characteristics**

**Driver**  $(V_{CC} = 5.0 \text{ V} \pm 5 \%, \text{ Ta} = 0 \text{ to} +75^{\circ}\text{C})$ 

Item		Symbol	Min	Max	Unit	Conditions
High Level Input Voltage		$V_{IH}$	2.0	_	V	
Low Level Input Voltage		V <sub>IL</sub>	_	0.8	٧	
Input Clamp Voltage		V <sub>IK</sub>	_	-1.5	٧	$V_{CC} = 4.75 \text{ V}, I_{IN} = -18 \text{ mA}$
High Level Output Voltage		$V_{OH}$	3.11	_	٧	$V_{CC} = 4.75 \text{ V}, V_{IH} = 2.0 \text{ V}$
						$I_{OH} = -59.3 \text{ mA (Ta} = 25^{\circ}\text{C)}$
			_	4.1		$V_{CC} = 5.25 \text{ V}, V_{IH} = 2.0 \text{ V}$
						$I_{OH} = -78.1 \text{ mA}$
Low Level Output Voltage		$V_{OL}$	_	0.15	V	$V_{CC} = 5.25 \text{ V}, V_{IL} = 0.8 \text{ V}$
						$I_{OL} = -0.24 \text{ mA}, V_{IH} = 4.5 \text{ V}$
High Level Input Current	DI	I <sub>IH</sub>	_	20	μΑ	$V_{CC} = 5.25 \text{ V}, V_{IH} = 2.7 \text{ V}$
	DE		_	60		$V_{CC} = 5.25 \text{ V}, V_{IH} = 2.7 \text{ V}$
Low Level Input Current	DI	I <sub>IL</sub>	_	-400	μΑ	$V_{CC} = 5.25 \text{ V}, V_{IL} = 0.4 \text{ V}$
	DE		_	-1200		$V_{CC} = 5.25 \text{ V}, V_{IL} = 0.4 \text{ V}$
High Level Output Current		I <sub>OH</sub>	_	100	μΑ	$V_{CC} = 4.75 \text{ V}, V_{IL} = 0 \text{ V}, V_{OH} = 5.0 \text{ V}$
			_	100		$V_{CC} = 4.75 \text{ V}, V_{IH} = 4.5 \text{ V}, V_{OH} = 5.0 \text{ V}$
Short Circuit Output Current	•	Ios	_	-30	mΑ	$V_{CC} = 5.25 \text{ V}, V_{IH} = 4.5 \text{ V}$

## **Receiver** (Ta = 0 to +75°C)

Item	Symbol	Min	Max	Unit	Con	ditions
High Level Output Threshold Voltage	V <sub>OTH</sub>	2.7	-(		$V_{CC} = 4.75 \text{ V}, V_{IL} = 1.15$ $I_{OH} = -400  \mu\text{A}$	V
Low Level Output Threshold Voltage	V <sub>OTL</sub>	-	0.5	V	$V_{CC} = 5.25 \text{ V}, V_{IH} = 1.55$ $I_{OL} = 8 \text{ mA}$	V
High Level Output Voltage	V <sub>OH</sub>	2.7	_		$V_{CC} = 4.75 \text{ V, V}_{IN}$ : Open $I_{OH} = -400  \mu\text{A}$	
Low Level Output Voltage	V <sub>OL</sub>		0.5	٧	V <sub>CC</sub> = 4.75 V	$I_{OL} = 8 \text{ mA}$
		_	0.4		V <sub>IH</sub> = 1.55 V	I <sub>OL</sub> = 4 mA
Input Resistance	R <sub>IN</sub>	7.4	20	ΚΩ	$V_{CC} = 0 V$	
High Level Input Current	I <sub>IH</sub>		0.42	mΑ	$V_{CC} = 4.75 \text{ V}, V_{IH} = 3.11$	V
Low Level Input Current	I <sub>IL</sub>	0.04	-0.24	mΑ	$V_{CC} = 5.25 \text{ V}, V_{IL} = 0.15$	V
Short Circuit Output Current	Ios	-20	-100	mΑ	$V_{CC} = 5.25 \text{ V}, V_{IL} = 0 \text{ V}$	

## **Driver/Receiver** (Ta = 0 to $+75^{\circ}$ C)

Item	Symbol	Min	Max	Unit	Conditions
Supply Voltage	I <sub>CCH</sub>	_	37	mΑ	$V_{CC} = 5.25 \text{ V}, V_{IH} = 4.5 \text{ V}$
	I <sub>CCL</sub>	_	55		$V_{CC} = 5.25 \text{ V}, V_{IL} = 0 \text{ V}$

# **Switching Characteristics**

**Driver**  $(V_{CC} = 5.0 \text{ V}, \text{Ta} = 25^{\circ}\text{C})$ 

Item	Symbol	Min	Max	Unit	Conditions
Rise Propagation Delay Time	t <sub>PLH</sub>	6.5	18.5	ns	$R_L = 47.5 \Omega$
Fall Propagation Delay Time	t <sub>PHL</sub>	6.5	18.5	ns	
Propagation Delay Time Difference*1	$\Delta t_{PD}$	_	10	ns	

Note: 1.  $\Delta t_{PD} = |t_{PLH} - t_{PHL}|$ 

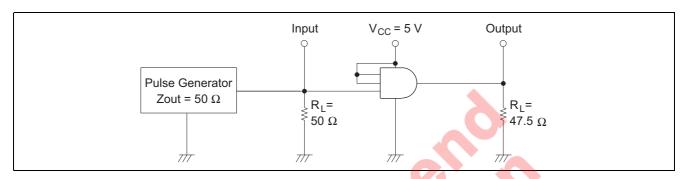
## Receiver ( $V_{CC} = 5.0 \text{ V}$ , $Ta = 25^{\circ}\text{C}$ )

Item	Symbol	Min	Max	Unit	Conditions
Rise Propagation Delay Time	t <sub>PLH</sub>	7.5	19.5	ns	$R_L = 2 \text{ K}\Omega, C_L = 15 \text{pF}$
Fall Propagation Delay Time	t <sub>PHL</sub>	7.5	19.5	ns	$R_L = 2 \text{ K}\Omega, C_L = 15 \text{pF}$
Propagation Delay Time Difference*1	$\Delta t_{PD}$	_	10	ns	$R_L = 2 \text{ K}\Omega, C_L = 15 \text{pF}$

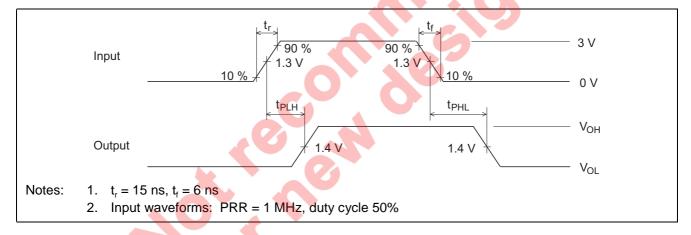
Note: 1.  $\Delta t_{PD} = |t_{PLH} - t_{PHL}|$ 

## Driver

## **Test Circuit**

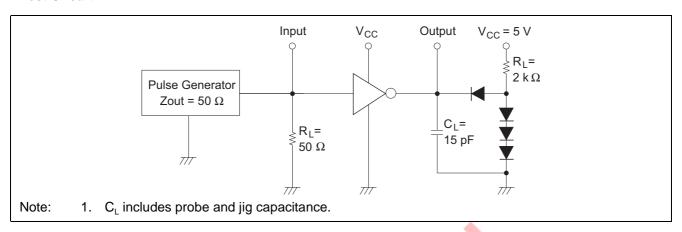


## **Waveforms**

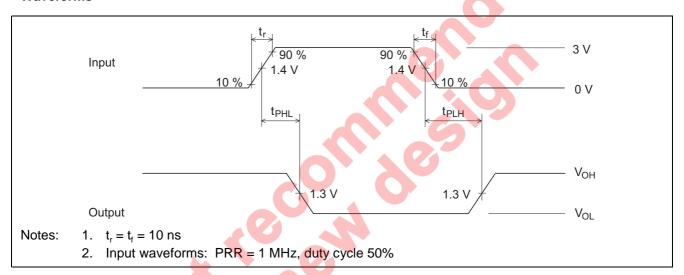


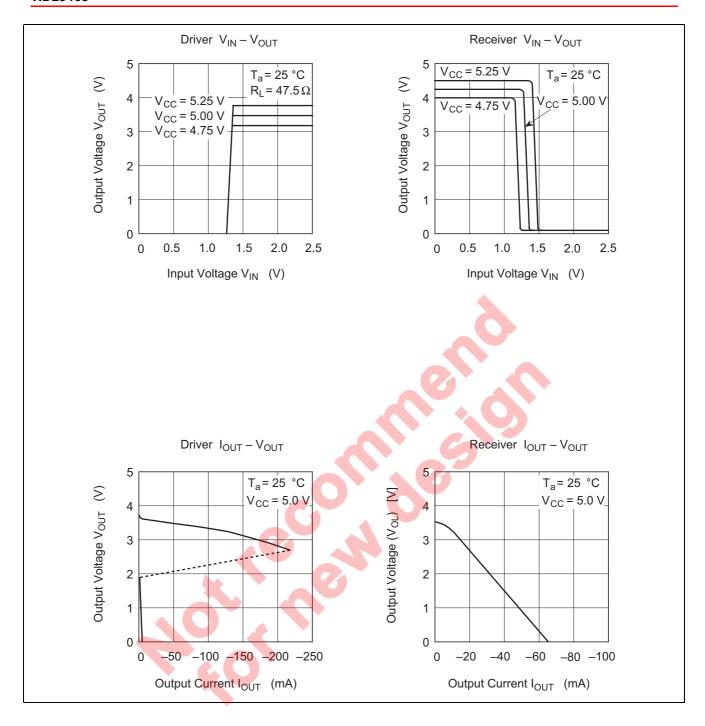
## Receiver

## **Test Circuit**

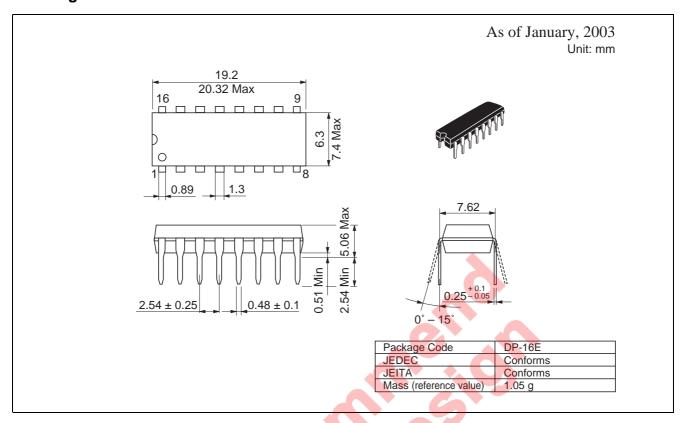


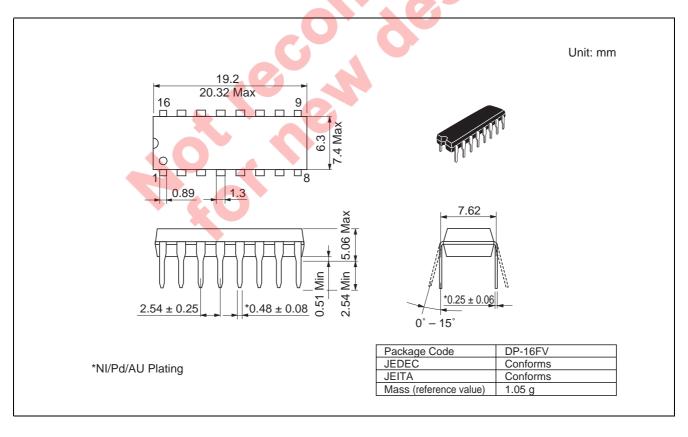
## **Waveforms**





## **Package Dimensions**





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